

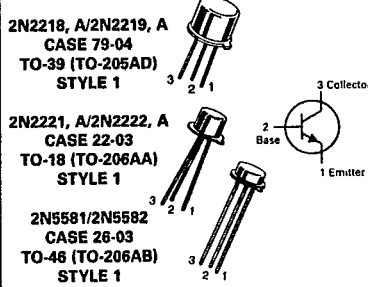
T-27-13
T-27-15
T-27-19

MAXIMUM RATINGS

Rating	Symbol	2N2218 2N2219 2N2221 2N2222	2N2218A 2N2219A 2N2221A 2N2222A	2N5581 2N5582	Unit
Collector-Emitter Voltage	V _{CEO}	30	40	40	V _{dc}
Collector-Base Voltage	V _{CBO}	60	75	75	V _{dc}
Emitter-Base Voltage	V _{EBO}	5.0	6.0	6.0	V _{dc}
Collector Current — Continuous	I _C	800	800	800	mAdc
		2N2218,A 2N2219,A	2N2221,A 2N2222,A	2N5581 2N5582	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	0.8 4.57	0.5 2.28	0.6 3.33	Watt mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	3.0 17.1	1.2 6.85	2.0 11.43	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200			°C

**2N2218, A/2N2219, A
2N2221, A/2N2222, A
2N5581/82**

JAN, JTX, JTXV AVAILABLE



**GENERAL PURPOSE
TRANSISTORS**
NPN SILICON

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (I _C = 10 mAdc, I _B = 0)	V _{(BR)CEO}	30 40	—	V _{dc}
		Non-A Suffix A-Suffix, 2N5581, 2N5582		
Collector-Base Breakdown Voltage (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	60 75	—	V _{dc}
		Non-A Suffix A-Suffix, 2N5581, 2N5582		
Emitter-Base Breakdown Voltage (I _E = 10 μAdc, I _C = 0)	V _{(BR)EBO}	5.0 6.0	—	V _{dc}
		Non-A Suffix A-Suffix, 2N5581, 2N5582		
Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB(off)} = 3.0 Vdc)	I _{CEX}	—	10	nAdc
		A-Suffix, 2N5581, 2N5582		
Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0)	I _{CBO}	—	0.01	μAdc
		Non-A Suffix A-Suffix, 2N5581, 2N5582		
		Non-A Suffix A-Suffix, 2N5581, 2N5582		
		Non-A Suffix A-Suffix, 2N5581, 2N5582		
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)	I _{EBO}	—	10	nAdc
		A-Suffix, 2N5581, 2N5582		
Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB(off)} = 3.0 Vdc)	I _{BL}	—	20	nAdc
		A-Suffix		
ON CHARACTERISTICS				
DC Current Gain (I _C = 0.1 mAdc, V _{CE} = 10 Vdc)	h _{FE}	20 35	—	—
		2N2218,A, 2N2221,A, 2N5581(1) 2N2219,A, 2N2222,A, 2N5582(1)		
(I _C = 1.0 mAdc, V _{CE} = 10 Vdc)		25 50	—	
		2N2218,A, 2N2221,A, 2N5581 2N2219,A, 2N2222,A, 2N5582		
(I _C = 10 mAdc, V _{CE} = 10 Vdc)		35 75	—	
		2N2218,A, 2N2221,A, 2N5581(1) 2N2219,A, 2N2222,A, 2N5582(1)		
(I _C = 10 mAdc, V _{CE} = 10 Vdc, T _A = -55°C)		15 35	—	
		2N2218,A, 2N2221,A, 2N5581 2N2219,A, 2N2222,A, 2N5582		
(I _C = 150 mAdc, V _{CE} = 10 Vdc)(1)		40 100	120 300	
		2N2218,A, 2N2221,A, 2N5581 2N2219,A, 2N2222,A, 2N5582		

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 7-27-19

ELECTRICAL CHARACTERISTICS (continued) ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
$(I_C = 150 \text{ mA}, V_{CE} = 1.0 \text{ Vdc})(1)$ 2N2218,A, 2N2221,A, 2N5581 2N2219,A, 2N2222,A, 2N5582		20 50	— —	
$(I_C = 500 \text{ mA}, V_{CE} = 10 \text{ Vdc})(1)$ 2N2218, 2N2221 2N2219, 2N2222 2N2218A, 2N2221A, 2N5581 2N2219A, 2N2222A, 2N5582		20 30 25 40	— — — —	
Collector-Emitter Saturation Voltage(1) $(I_C = 150 \text{ mA}, I_B = 15 \text{ mA})$	$V_{CE(sat)}$	—	0.4	Vdc
	Non-A Suffix A-Suffix, 2N5581, 2N5582	—	0.3	
$(I_C = 500 \text{ mA}, I_B = 50 \text{ mA})$	Non-A Suffix A-Suffix, 2N5581, 2N5582	—	1.6 1.0	
Base-Emitter Saturation Voltage(1) $(I_C = 150 \text{ mA}, I_B = 15 \text{ mA})$	$V_{BE(sat)}$	0.6 0.6	1.3 1.2	Vdc
	Non-A Suffix A-Suffix, 2N5581, 2N5582	—	2.6 2.0	
	Non-A Suffix A-Suffix, 2N5581, 2N5582	—	2.6 2.0	

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product(2) $(I_C = 20 \text{ mA}, V_{CE} = 20 \text{ Vdc}, f = 100 \text{ MHz})$	All Types, Except 2N2219A, 2N2222A, 2N5582	f_T	250 300	— —	MHz
Output Capacitance(3) $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 100 \text{ kHz})$		C_{obo}	—	8.0	pF
Input Capacitance(3) $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 100 \text{ kHz})$	Non-A Suffix A-Suffix, 2N5581, 2N5582	C_{ibo}	—	30 25	pF
Input Impedance $(I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A	h_{ie}	1.0 2.0	3.5 8.0	kohms
$(I_C = 10 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A		0.2 0.25	1.0 1.25	
Voltage Feedback Ratio $(I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A	h_{re}	—	5.0 8.0	$\times 10^{-4}$
$(I_C = 10 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A		—	2.5 4.0	
Small-Signal Current Gain $(I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A	h_{fe}	30 50	150 300	—
$(I_C = 10 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A		50 75	300 375	
Output Admittance $(I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A	h_{oe}	3.0 5.0	15 35	μmhos
$(I_C = 10 \text{ mA}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	2N2218A, 2N2221A 2N2219A, 2N2222A		10 25	100 200	
Collector Base Time Constant $(I_E = 20 \text{ mA}, V_{CB} = 20 \text{ Vdc}, f = 31.8 \text{ MHz})$	A-Suffix	$r_b'C_c$	—	150	ps
Noise Figure $(I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ Vdc}, R_S = 1.0 \text{ kohm}, f = 1.0 \text{ kHz})$	2N2222A	NF	—	4.0	dB
Real Part of Common-Emitter High Frequency Input Impedance $(I_C = 20 \text{ mA}, V_{CE} = 20 \text{ Vdc}, f = 300 \text{ MHz})$	2N2218A, 2N2219A 2N2221A, 2N2222A	$Re(h_{ie})$	—	60	Ohms

(1) Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.
 (2) f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.
 (3) 2N5581 and 2N5582 are Listed C_{cb} and C_{eb} for these conditions and values.

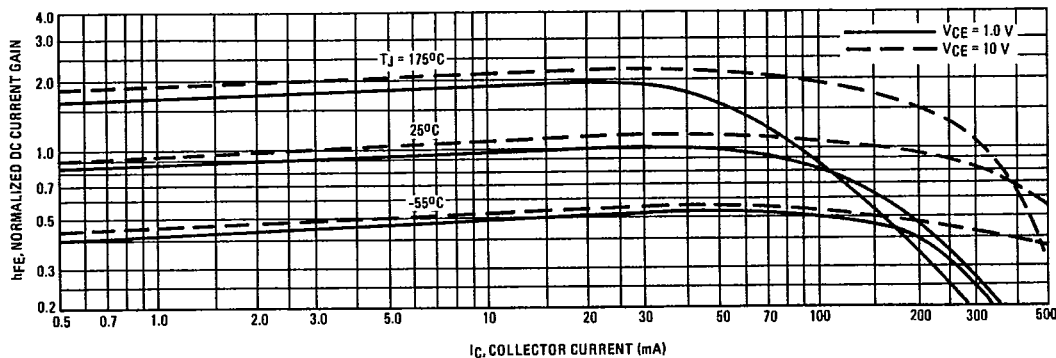
2N2218/19/21/22, A SERIES, 2N5581/82

ELECTRICAL CHARACTERISTICS (continued) (T_A = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
SWITCHING CHARACTERISTICS				
Delay Time	(V _{CC} = 30 Vdc, V _{BE(off)} = 0.5 Vdc, I _C = 150 mA, I _{B1} = 15 mA) (Figure 14)	t _d	—	10 ns
Rise Time		t _r	—	25 ns
Storage Time	(V _{CC} = 30 Vdc, I _C = 150 mA, I _{B1} = I _{B2} = 15 mA) (Figure 15)	t _s	—	225 ns
Fall Time		t _f	—	60 ns
Active Region Time Constant (I _C = 150 mA, V _{CE} = 30 Vdc) (See Figure 12 for 2N2218A, 2N2219A, 2N2221A, 2N2222A)	T _A	—	2.5	ns

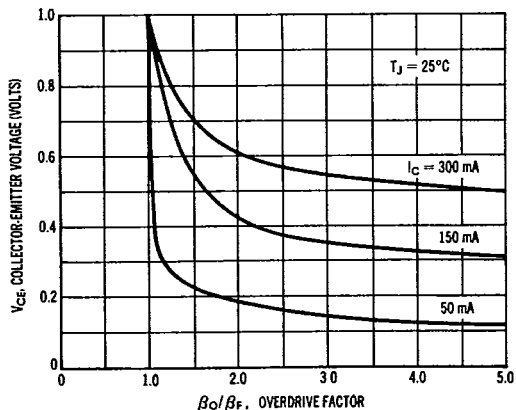
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FIGURE 1 - NORMALIZED DC CURRENT GAIN



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FIGURE 2 - COLLECTOR CHARACTERISTICS IN SATURATION REGION



This graph shows the effect of base current on collector current. β₀ (current gain at the edge of saturation) is the current gain of the transistor at 1 volt, and β_F (forced gain) is the ratio of I_C/I_B in a circuit.

EXAMPLE: For type 2N2219, estimate a base current (I_B) to insure saturation at a temperature of 25°C and a collector current of 150 mA.

Observe that at I_C = 150 mA an overdrive factor of at least 2.5 is required to drive the transistor well into the saturation region. From Figure 1, it is seen that h_{FE} @ 1 volt is approximately 0.62 of h_{FE} @ 10 volts. Using the guaranteed minimum gain of 100 @ 150 mA and 10 V, β₀ = 62 and substituting values in the overdrive equation, we find:

$$\frac{\beta_0}{\beta_F} = \frac{h_{FE} @ 1.0V}{I_C/I_B} \quad 2.5 = \frac{62}{150/I_B} \quad I_B \approx 6.0 \text{ mA}$$

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FIGURE 3 - "ON" VOLTAGES

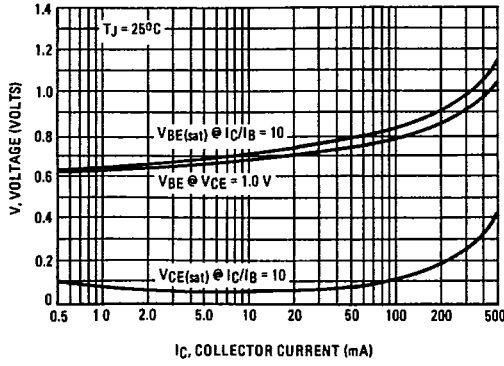
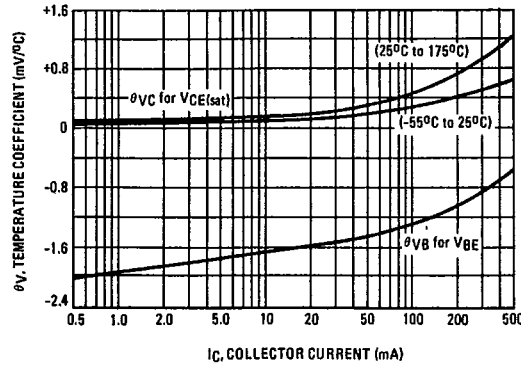


FIGURE 4 - TEMPERATURE COEFFICIENTS



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h PARAMETERS

$V_{CE} = 10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$, $T_A = 25^\circ\text{C}$

This group of graphs illustrates the relationship between h_{fe} and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were selected and the same units were used to develop the correspondingly numbered curves on each graph.

FIGURE 5 - INPUT IMPEDANCE

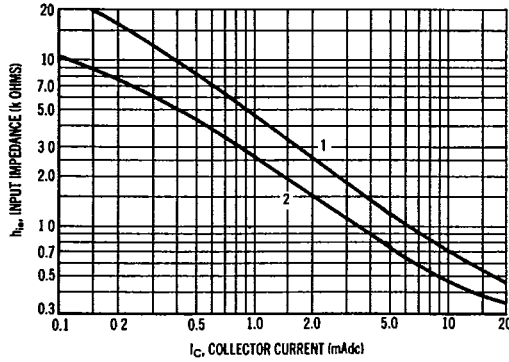


FIGURE 6 - VOLTAGE FEEDBACK RATIO

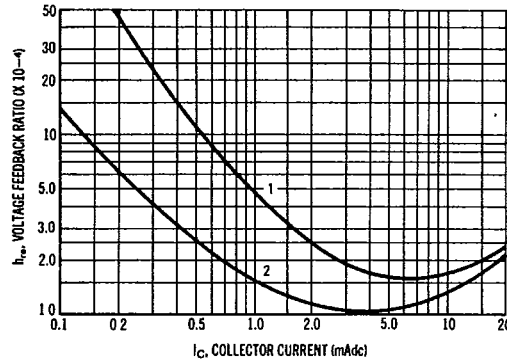


FIGURE 7 - CURRENT GAIN

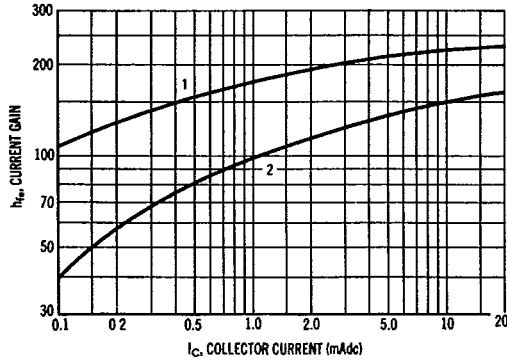
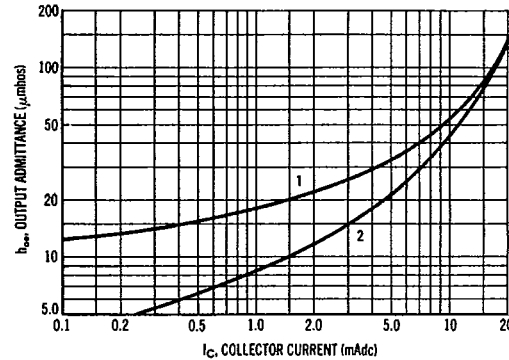


FIGURE 8 - OUTPUT ADMITTANCE



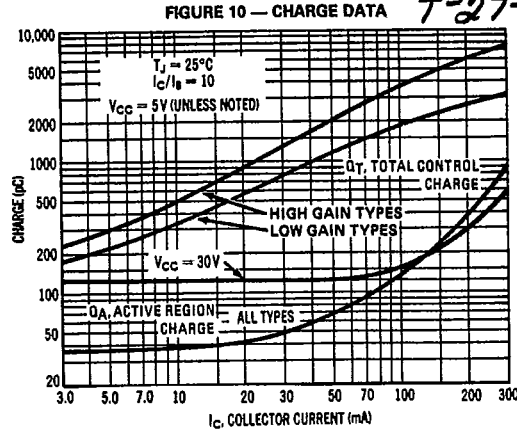
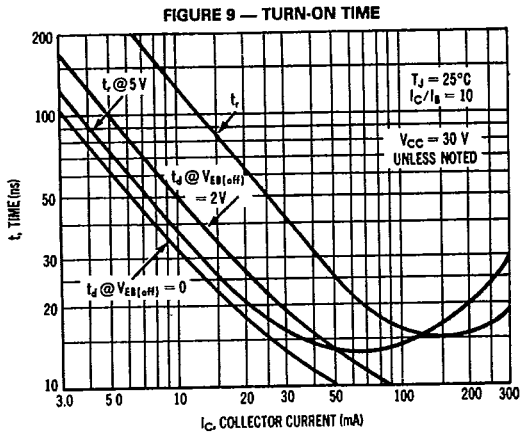
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SWITCHING TIME CHARACTERISTICS

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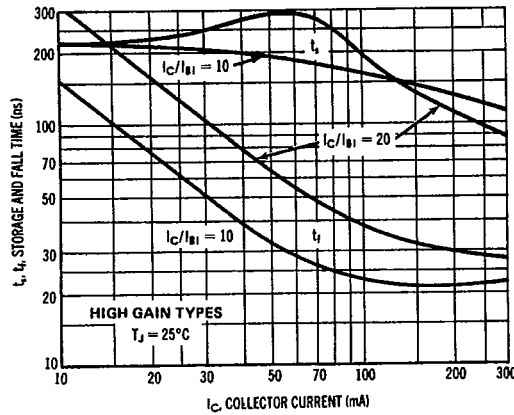
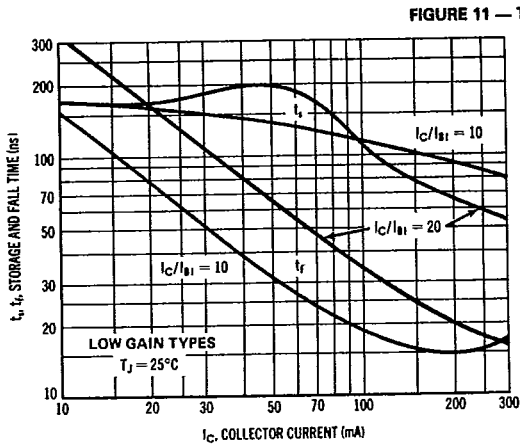


FIGURE 12 — DELAY AND RISE TIME EQUIVALENT TEST CIRCUIT

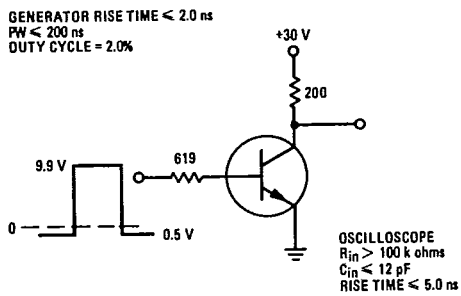


FIGURE 13 — STORAGE TIME AND FALL TIME EQUIVALENT TEST CIRCUIT

